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Dual 2 A, 1.2 V, Slew Rate Controlled Load Switch

DESCRIPTION

SiP32413, SiP32414 and SiP32416 are slew rate controlled load switches that is designed for 1.1 V to 5.5 V operation.

The devices guarantee low switch on-resistance at 1.2 V input. SiP32413 and SiP32414 feature a controlled soft-on slew rate of typical 150 µs that limits the inrush current for designs of capacitive load or noise sensitive loads. SiP32416 features a longer slew rate of typical 2.5 ms to keep the peak of the inrush current even lower.

The devices feature a low voltage control logic interface (On/Off interface) that can interface with low voltage digital control without extra level shifting circuit. The SiP32414 and SiP32416 also integrate output discharge switches that enable fast shutdown load discharge. When the switches are off, they provide the reverse blocking to prevent high current flowing into the power source.

All SiP32413, SiP32414 and SiP32416 are available in TDFN8 2 mm x 2 mm package. Each switch in each device can support over 2 A of continuous current.

TYPICAL APPLICATION CIRCUIT

FEATURES

- Halogen-free according to IEC 61249-2-21 definition
- 1.1 V to 5.5 V operation voltage range
- 62 mΩ typical from 2 V to 5 V
- Low R_{ON} down to 1.2 V
- Slew rate controlled turn-on: 150 µs at 3.6 V for SiP32413, SiP32414 2.5 ms at 3.6 V for SiP32416
- Fast shutdown load discharge for SiP32414 and SiP32416
- Low guiescent current < 1 µA when disabled $6.7 \ \mu A$ at $V_{IN} = 1.2 \ V$
- Switch off reversed blocking
- Compliant to RoHS Directive 2002/95/EC

APPLICATIONS

- Cellular phones
- Portable media players
- Digital camera
- GPS
- Computers
- Portable instruments and healthcare devices

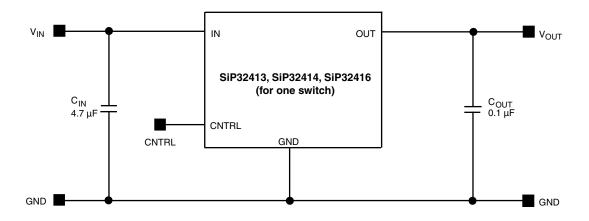


Figure 1 - SiP32413, SiP32414, SiP32416 Typical Application Circuit



COMPLIANT HALOGEN FREE



ORDERING INFORMATION					
Temperature Range	Package	Marking	Part Number		
- 40 °C to 85 °C	TDFN8 2 mm x 2 mm	AA	SiP32413DNP-T1-GE4		
		AB	SiP32414DNP-T1-GE4		
		AG	SiP32416DNP-T1-GE4		

Note:

GE4 denotes halogen-free and RoHS compliant

ABSOLUTE MAXIMUM RATINGS				
Parameter	Limit	Unit		
Supply Input Voltage (VIN)	- 0.3 to 6			
Enable Input Voltage (V _{EN})	- 0.3 to 6	V		
Output Voltage (V _{OUT})	- 0.3 to 6			
Maximum Continuous Switch Current (I _{max.})	2.4	A		
Maximum Pulsed Current (Pulsed at 1 ms, 10 % Duty Cycle)	3			
ESD Rating (HBM)	4000	V		
Storage Temperature (T _{stg})	- 65 to 150	°C		
Thermal Resistance $(\theta_{JA})^a$	95	°C/W		
Power Dissipation (P _D) ^{a, b}	580	mW		

Notes:

a. Device mounted with all leads and power pad soldered or welded to PC board, see PCB layout.

b. Derate 10.5 mW/°C above $T_A = 70$ °C, see PCB layout.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating/conditions for extended periods may affect device reliability.

RECOMMENDED OPERATING RANGE				
Parameter	Limit	Unit		
Input Voltage Range (V _{IN})	1.1 to 5.5	V		
Operating Junction Temperature Range (T _J)	- 40 to 125	C°		



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SiP32413, SiP32414, SiP32416

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		Test Conditions Unless Specified $V_{IN} = 5 \text{ V}, \text{ T}_{A} = -40 ^{\circ}\text{C} \text{ to } 85 ^{\circ}\text{C}$		Limits - 40 °C to 85 °C				
Parameter		Symbol	(Typical values are at $T_A = 25 \text{ °C}$)	Min. ^a Typ. ^b		Max. ^a	Unit	
Operating Voltage ^c		V _{IN}		1.1	-	5.5	V	
			V _{IN} = 1.2 V, CNTRL = active	-	6.7	14		
			V _{IN} = 1.8 V, CNTRL = active	-	14	24		
			$V_{IN} = 2.5 V, CNTRL = active$	-	25	40		
Quiescent Current		Ι _Q	V _{IN} = 3.6 V, CNTRL = active	-	40	60		
			V _{IN} = 4.3 V, CNTRL = active	-	52	75	μΑ	
			V _{IN} = 5 V, CNTRL = active	-	71	99	- ·	
Off Supply Current		I _{Q(off)}	CNTRL = inactive, OUT = open	-	-	1		
Off Switch Current		I _{DS(off)}	CNTRL = inactive, OUT = 0	-	-	1	1	
Reverse Blocking Current		I _{RB}	$V_{OUT} = 5 \text{ V}, V_{IN} = 1.2 \text{ V}, V_{EN} = \text{inactive}$	-	-	10	_	
-		110	$V_{IN} = 1.2 \text{ V}, I_L = 100 \text{ mA}, T_A = 25 \text{ °C}$	-	66	76	+	
			$V_{IN} = 1.8 \text{ V}, I_{L} = 100 \text{ mA}, T_{A} = 25 \text{ °C}$	-	62	72		
			$V_{IN} = 2.5 \text{ V}, I_L = 100 \text{ mA}, T_A = 25 \text{ °C}$	-	62	72	mΩ	
On-Resistance		R _{DS(on)}	$V_{IN} = 3.6 \text{ V}, I_L = 100 \text{ mA}, T_A = 25 \text{ °C}$	-	62	72		
			$V_{IN} = 4.3 \text{ V}, I_L = 100 \text{ mA}, T_A = 25 \text{ °C}$	-	62	72		
			$V_{IN} = 5 \text{ V}, I_{L} = 100 \text{ mA}, T_{A} = 25 \text{ °C}$	-	62	72		
On-Resistance TempCoefficient		TC _{RDS}		-	3900	-	ppm/°	
		. ORDS	V _{IN} = 1.2 V	-	-	0.3		
			$V_{\rm IN} = 1.8 \text{ V}$	-	-	0.4 ^d		
		V _{IL}	V _{IN} = 2.5 V	-	-	0.5 ^d	-	
CNTRL Input Low Voltage ^c			V _{IN} = 3.6 V	-	-	0.6 ^d		
			$V_{IN} = 4.3 \text{ V}$	-	-	0.7 ^d		
			$V_{\rm IN} = 5 V$	-	-	0.8 ^d		
			V _{IN} = 1.2 V	0.9 ^d	_	-	- V	
			V _{IN} = 1.8 V	1.2 ^d	-	-	-	
			V _{IN} = 2.5 V	1.4 ^d	-	-		
CNTRL Input High Voltage ^c		V _{IH}	V _{IN} = 3.6 V	1.6 ^d	-	-		
			V _{IN} = 4.3 V	1.7 ^d	-	-		
			V _{IN} = 5 V	1.8	-	-	_	
EN Input Leakage		I _{SINK}	V _{EN} = 5.5 V	-	-	1	μA	
Output Pulldown Resistance		R _{PD}	CNTRL = inactive, $T_A = 25 \text{ °C}$ (SiP32414 and SiP32416 only)	-	217	280	Ω	
Output Turn-On Delay Time	0.000	t _{d(on)}		-	140	210	μs	
Output Turn-On Rise Time	SiP32413, SiP32414	t _(on)	1	80	150	220		
Output Turn-Off Delay Time	51732414	t _{d(off)}	V _{IN} = 3.6 V, R _{LOAD} = 10 Ω,	-	0.27	1	1	
Output Turn-On Delay Time		t _{d(on)}	$C_{LOAD} = 0.1 \ \mu\text{F}, T_A = 25 \ ^{\circ}\text{C}$	-	2	-	ms	
Output Turn-On Rise Time	SiP32416	t _(on)		1.2	2.5	3.8		
Output Turn-Off Delay Time		t _{d(off)}	· · · · · · · · · · · · · · · · · · ·		-	0.001	-	

Notes:

a. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum.

b. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.

c. For V_{IN} outside this range consult typical EN threshold curve.

d. Not tested, guarantee by design.



PIN CONFIGURATION

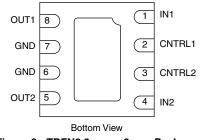


Figure 2 - TDFN8 2 mm x 2 mm Package

PIN DESCRIPTION					
Pin Number	Name	Function			
1	IN1	This is the input pin of the switch side 1			
2	CNTRL1	This is the control pin of the switch side 1			
3	CNTRL2	This is the control pin of the switch side 2			
4	IN2	This is the input pin of the switch side 2			
5	OUT2	This is the output pin of the switch side 2			
6	GND	Ground connection			
7	GND	Ground connection			
8	OUT1	This is the output pin of the switch side 1			

TRUTH TABLE SiP32413					
CNTRL1	CNTRL2	SW1	SW2		
0	0	ON	OFF		
0	1	ON	ON		
1	0	OFF	OFF		
1	1	OFF	ON		

TRUTH TABLE SiP32414, SiP32416					
CNTRL1	CNTRL2	SW1	SW2		
0	0	OFF	OFF		
0	1	OFF	ON		
1	0	ON	OFF		
1	1	ON	ON		

TYPICAL CHARACTERISTICS (internally regulated, 25 °C, unless otherwise noted)

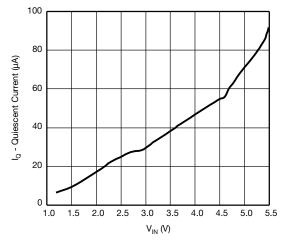
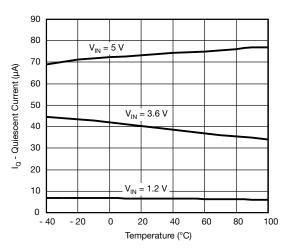


Figure 3 - Quiescent Current vs. Input Voltage





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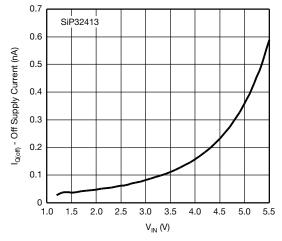


Figure 5 - SiP32413 Off Supply Current vs. $\ensuremath{V_{\text{IN}}}$

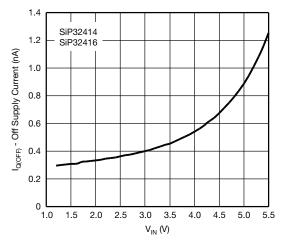
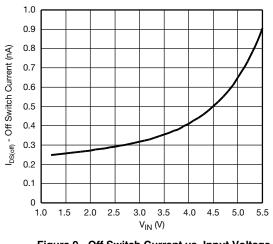


Figure 7 - SiP32414 and SiP32416 Off Supply Current vs. V_{IN}





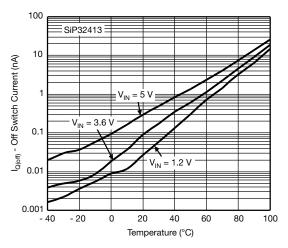


Figure 6 - SiP32414 Off Supply Current vs. Temperature

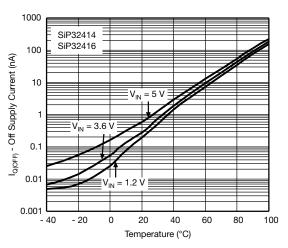


Figure 8 - SiP32414 and SiP32416 Off Supply Current vs. Temperature

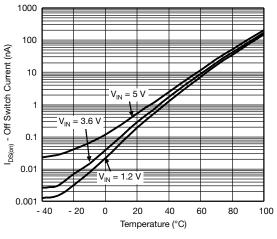


Figure 10 - Off Switch Current vs. Temperature

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TYPICAL CHARACTERISTICS (internally regulated, 25 °C, unless otherwise noted)

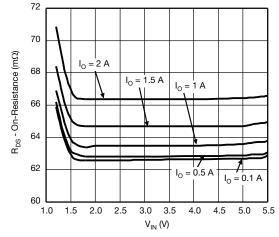


Figure 11 - R_{DS(on)} vs. Input Voltage

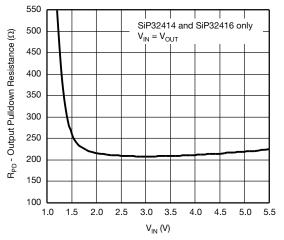


Figure 13 - SiP32414 and SiP32416 Output Pull Down vs. Input Voltage

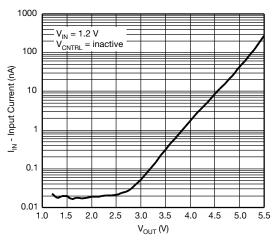


Figure 15 - Reverse Blocking Current vs. Output Voltage

75 I₀ = 0.1 A 70 V_{IN} = 5 V R_{DS} - On-Resistance (mΩ) 65 60 55 50 45 40 - 20 0 40 60 100 40 20 80 Temperature (°C)

Figure 12 - R_{DS(on)} vs. Temperature

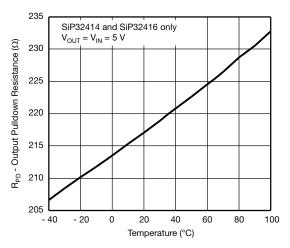


Figure 14 - SiP32414 and SiP32416 Output Pull Down vs. Temperature

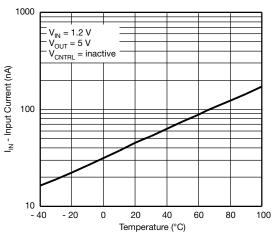


Figure 16 - Reverse Blocking Current vs. Temperature

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TYPICAL CHARACTERISTICS (internally regulated, 25 °C, unless otherwise noted)

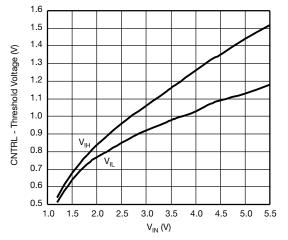


Figure 17 - CNTRL Threshold Voltage vs. Input Voltage

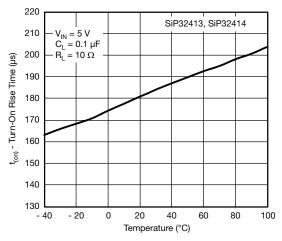


Figure 19 - SiP32413 and SiP32414 Rise Time vs. Temperature

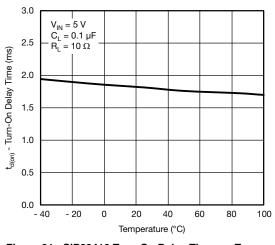


Figure 21 - SiP32416 Turn-On Delay Time vs. Temperature

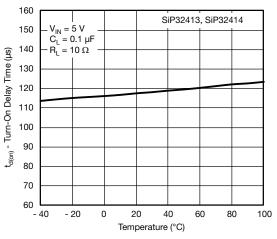


Figure 18 - SiP32413 and SiP32414 Turn-On Delay Time vs. Temperature

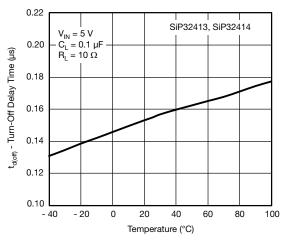


Figure 20 - SiP32413 and SiP32414 Turn-Off Delay Time vs. Temperature

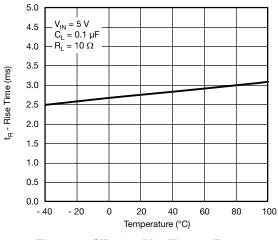


Figure 22 - SiP32416 Rise Time vs. Temperature

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TYPICAL WAVEFORMS



TYPICAL CHARACTERISTICS (internally regulated, 25 °C, unless otherwise noted)

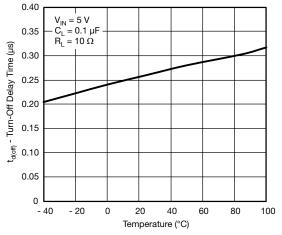


Figure 23 - SiP32416 Turn-Off Delay Time vs. Temperature

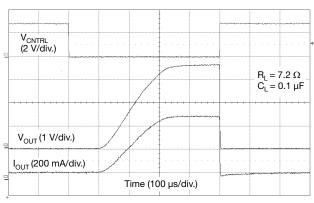
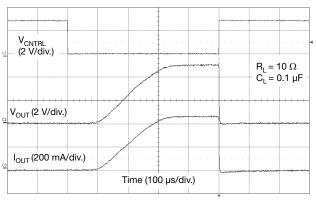
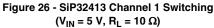


Figure 24 - SiP32413 Channel 1 Switching (V_{IN} = 3.6 V, R_L = 7.2 Ω)





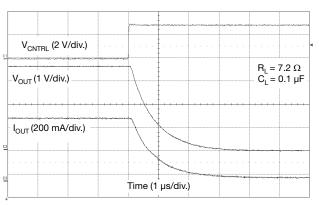
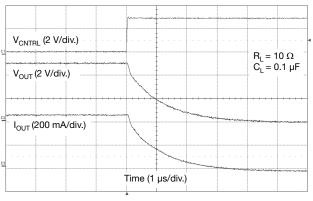
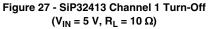


Figure 25 - SiP32413 Channel 1 Turn-Off $(V_{IN} = 3.6 \text{ V}, \text{ R}_{L} = 7.2 \Omega)$







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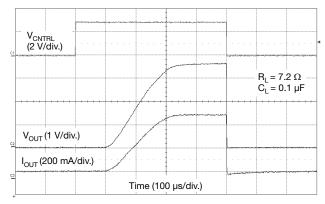


Figure 28 - SiP32413 Channel 2 and SiP32414 Switching $(V_{IN} = 3.6 V, R_{L} = 7.2 \Omega)$

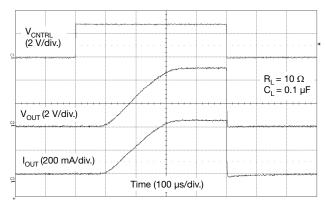
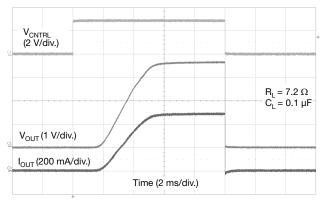
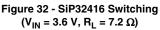


Figure 30 - SiP32413 Channel 2 and SiP32414 Switching $(V_{IN} = 5 V, R_L = 10 \Omega)$





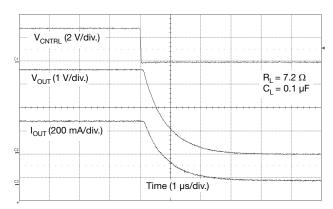


Figure 29 - SiP32413 Channel 2 and SiP32414 Turn-Off $(V_{IN} = 3.6 \text{ V}, \text{ R}_{L} = 7.2 \Omega)$

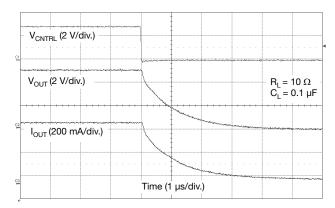
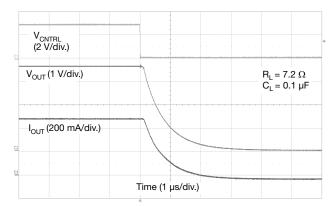
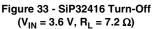
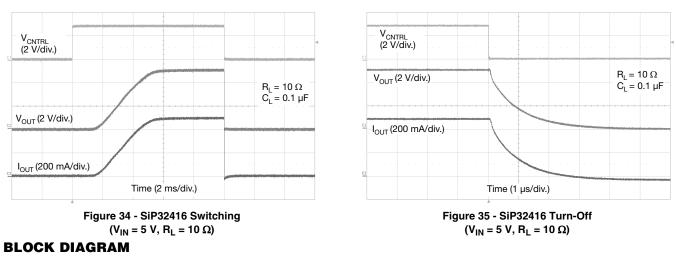


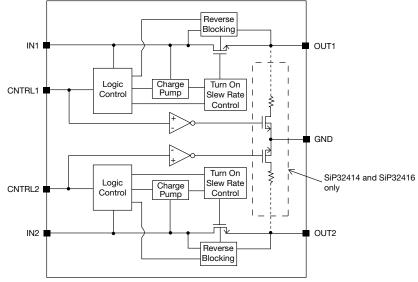
Figure 31 - SiP32413 Channel 2 and SiP32414 Turn-Off $(V_{IN} = 5 V, R_L = 10 \Omega)$

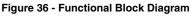




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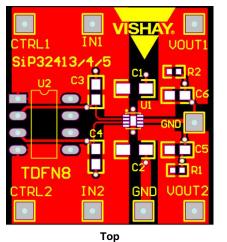


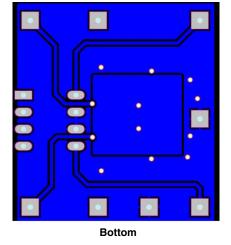


PCB LAYOUT

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Figure 37 - PCB Layout for TDFN8 2 mm x 2 mm (type: FR4, size: 1.2" x 1.3", thickness: 0.062", copper thickness: 2 oz.)



DETAILED DESCRIPTION

SiP32413, SiP32414 and SiP32416 are dual n-channel power MOSFETs designed as high side load switch with slew rate control to prevent in-rush current. Once enable the device charges the gate of the power MOSFET to 5 V gate to source voltage while controlling the slew rate of the turn on time. The mostly constant gate to source voltage keeps the on resistance low through out the input voltage range. For SiP32414, when disable the output discharge circuit turns on to help pull the output voltage to ground more quickly. For all parts, in disable mode, the reverse blocking circuit is activated to prevent current from going back to the input in case the output voltage is higher than the input voltage. Input voltage is needed for the reverse blocking circuit to work properly, it can be as low as $V_{IN(min.)}$.

APPLICATION INFORMATION

Input Capacitor

While bypass capacitors on the inputs are not required, 2.2 μ F or larger capacitors for C_{IN} is recommended in almost all applications. The bypass capacitors should be placed as physically close as possible to the device's input to be effective in minimizing transients on the input. Ceramic capacitors are recommended over tantalum because of their ability to withstand input current surges from low impedance sources such as batteries in portable devices.

Output Capacitor

A 0.1 μ F capacitor or larger across V_{OUT} and GND is recommended to insure proper slew operation. C_{OUT} may be increased without limit to accommodate any load transient condition with only minimal affect on the turn on slew rate time. There are no ESR or capacitor type requirement.

Control

The CNTRL pins are compatible with both TTL and CMOS logic voltage levels.

Protection Against Reverse Voltage Condition

SiP32413, SiP32414 and SiP32416 contain reverse blocking circuitries to protect the current from going to the input from the output in case where the output voltage is higher than the input voltage when the main switch is off. Supply voltages as low as the minimum required input voltage are necessary for these circuitries to work properly.

Thermal Considerations

All three parts are designed to maintain constant output load current. Due to physical limitations of the layout and assembly of the device the maximum switch current is 2.4 A, as stated in the Absolute Maximum Ratings table. However, another limiting characteristic for the safe operating load current is the thermal power dissipation of the package. To obtain the highest power dissipation (and a thermal resistance of 95) the power pad of the device should be connected to a heat sink on the printed circuit board. The maximum power dissipation in any application is dependant on the maximum junction temperature, $T_{J(max.)} = 125 \text{ °C}$, the junction-to-ambient thermal resistance for the TDFN4 1.2 mm x 1.6 mm package, $\theta_{J-A} = 95 \text{ °C/W}$, and the ambient temperature, T_A , which may be formulaically expressed as:

P (max.) =
$$\frac{T_{J} (max.) - T_{A}}{\theta_{J-A}} = \frac{125 - T_{A}}{95}$$

It then follows that, assuming an ambient temperature of 70 $^{\rm o}\text{C},$ the maximum power dissipation will be limited to about 580 mW.

So long as the load current is below the 2.4 A limit, the maximum continuous switch current becomes a function two things: the package power dissipation and the $R_{DS(ON)}$ at the ambient temperature.

As an example let us calculate the worst case maximum load current at $T_A = 70$ °C. The worst case $R_{DS(ON)}$ at 25 °C occurs at an input voltage of 1.2 V and is equal to 75 m Ω . The $R_{DS(ON)}$ at 70 °C can be extrapolated from this data using the following formula:

 $R_{DS(ON)}$ (at 70 °C) = $R_{DS(ON)}$ (at 25 °C) x (1 + $T_C x \Delta T$)

Where T_C is 3400 ppm/°C. Continuing with the calculation we have

 $\mathsf{R}_{\mathsf{DS}(\mathsf{ON})}$ (at 70 °C) = 75 m Ω x (1 + 0.0034 x (70 °C - 25 °C)) = 86.5 m Ω

The maximum current limit is then determined by

$$I_{LOAD}$$
 (max.) < $\sqrt{\frac{P(max.)}{R_{DS}(ON)}}$

which in case is 2.6 A, assuming one switch turn on at a time. Under the stated input voltage condition, if the 2.6 A current limit is exceeded the internal die temperature will rise and eventually, possibly damage the device.

To avoid possible permanent damage to the device and keep a reasonable design margin, it is recommended to operate the device maximum up to 2.4 A only as listed in the Absolute Maximum Ratings table.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <u>www.vishay.com/ppg?71437</u>.

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MIN.

0.020

0.000

MAX.

0.60

0.05

Vishay Siliconix

INCHES

NOM.

0.022

-

MAX.

0.024

0.002

0.011

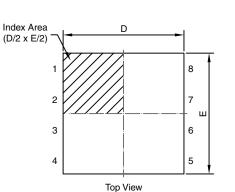
0.081

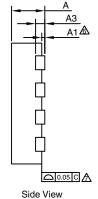
0.033

0.081

0.016

CASE OUTLINE FOR TDFN8 2 x 2





	A3	(0.152 REF	0.006 REF			
	b	0.18	0.23	0.28	0.007	0.009	
	D	1.95	2.00	2.05	0.077	0.079	
	D2	0.75	0.80	0.85	0.030	0.031	
	е		0.50 BSC	0.020 BSC			
	E	1.95	2.00	2.05	0.077	0.079	
	E2	1.40	1.45	1.50	0.055	0.057	
2	К	-	0.20	-	-	0.008	
	L	0.30	0.35	0.40	0.012	0.014	
	ECN: C11-0033 Rev. A, 07-Feb-11						
	DWG: 5	5997					

MILLIMETERS

NOM.

0.55

-

MIN.

0.50

0.00

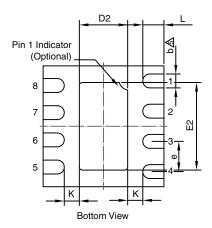
Note

DIM.

А

A1

- 1. All dimensions are in millimeters which will govern.
- 2. Max. package warpage is 0.05 mm.
- 3. Max. allowable burrs is 0.076 mm in all directions.
- 4. Pin #1 ID on top will be laser/ink marked.
- △ Dimension applies to meatlized terminal and is measured between 0.20 mm and 0.25 mm from terminal tip.
- Applied only for terminals.
- \triangle Applied for exposed pad and terminals.





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